

SANYO Semiconductors DATA SHEET

SBT80-06JS-

Schottky Barrier Diode (Twin Type • Cathode Common)

60V, 8A Rectifier

Applications

· High frequency rectification (switching regulators, converters, choppers).

Features

- Guaranteed up to Tj=150°C.
- Low forward voltage (VF max=0.58V).
- · Short reverse recovery time.
- · Low switching noise.
- · High reliability due to highly reliable planar structure.
- · Attachment workability is good by Mica-less package.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		60	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		66	V
Average Output Current	IO	50Hz resistive load, sine wave Tc=109°C	8	Α
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	80	Α
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Syllibol		min	typ	max	Unit
Reverse Voltage	VR	I _R =1mA, Tj=25°C *	60			V
Forward Voltage	VF	IF=3.0A, Tj=25°C *			0.58	V
Reverse Current	IR	V _R =30V, Tj=25°C *			0.1	mA

Note) *: Value per element

Continued on next page.

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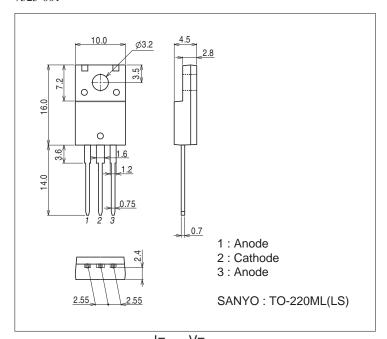
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oniii
Interterminal Capacitance	С	V _R =10V, Tj=25°C *		130		pF
Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC			5.0	°C / W

100

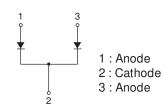
Note) *: Value per element

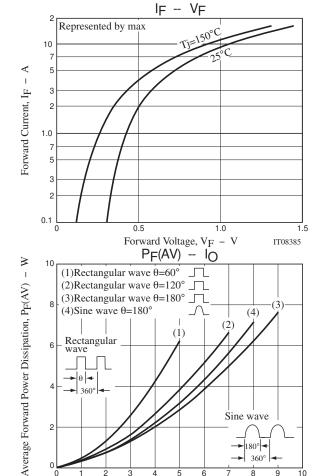
Package Dimensions

unit : mm (typ) 7525-001



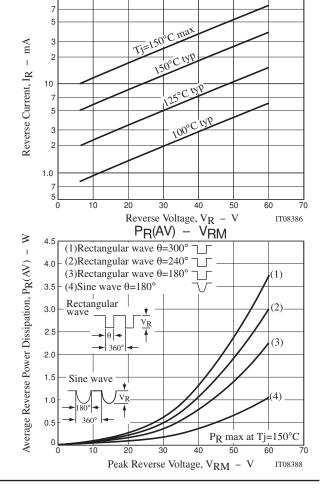
Electrical Connection

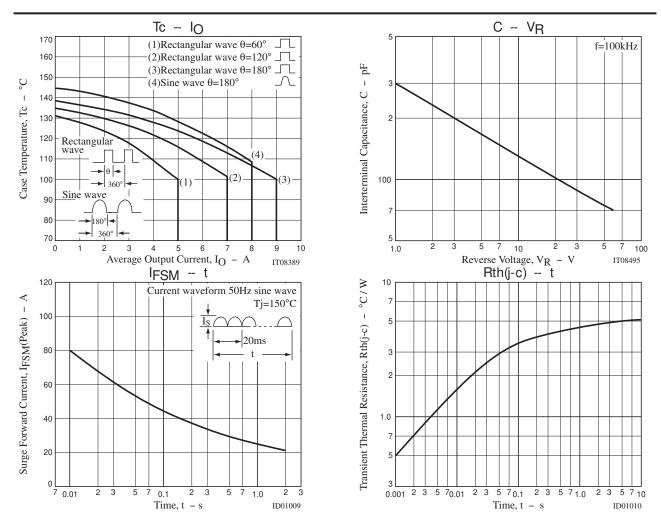




Average Output Current, IO - A

IT08387





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